Vishay Semiconductors

High Performance Schottky Rectifier, 1 A

FEATURES

- · Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-10MQ100NTRPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS VALUES U					
I _{F(AV)}	Rectangular waveform	1	А			
V _{RRM}		100	V			
I _{FSM}	$t_p = 5 \ \mu s \ sine$	120	А			
V _F	1.5 A _{pk} , T _J = 125 °C	0.68	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-10MQ100NTRPbF	UNITS		
Maximum DC reverse voltage	V _R	100 V			
Maximum working peak reverse voltage	V _{RWM}	100	V		

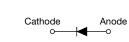
ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS			
Maximum average forward current		50 % duty cycle at T_L = 126 °C, On PC board 9 mm ² island (0.013	1.5	<u>,</u>		
See fig. 4	I _{F(AV)}	50 % duty cycle at T _L = 135 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		1	A	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load	120		
non-repetitive surge current, $T_J = 25 \text{ °C}$ I_{FSM} See fig. 6		10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	30	A	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 8 mH		1.0	mJ	
Repetitive avalanche current	I _{AR}			0.5	А	

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COMPLIANT





SMA (DO-214AC)

PRODUCT SUMMARY			
Package	SMA (DO-214AC)		
I _{F(AV)}	1 A		
V _R	100 V		
V _F at I _F	0.78 V		
I _{RM}	1 mA at 125 °C		
T _J max.	150 °C		
Diode variation	Single		
E _{AS}	1.0 mJ		





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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST C	ONDITIONS	VALUES	UNITS
		1 A	T _{.1} = 25 °C	0.78	V
Maximum forward voltage drop	V _{EM} ⁽¹⁾	1.5 A		0.85	
See fig. 1	VFM ("	1 A	T 105 %C	0.63	
		1.5 A	— T _J = 125 °C	0.68	
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	V Deted V	0.1	mA
See fig. 2	IRM \''	T _J = 125 °C	V _R = Rated V _R	1	
Threshold voltage	V _{F(TO)}	$T_{\rm J} = T_{\rm J} \text{ maximum} \qquad \qquad$		0.52	V
Forward slope resistance	r _t			mΩ	
Typical junction capacitance	CT	$V_R = 10 V_{DC}$, $T_J = 25 \text{ °C}$, test signal = 1 MHz		38	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 2.0		nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W	
Approximate weight			0.07	g	
Approximate weight			0.002	oz.	
Marking device		Case style SMA (DO-214AC)(similar D-64)	1,	J	

Note

(1)

 $\frac{dP_{tot}}{dT_{J}} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



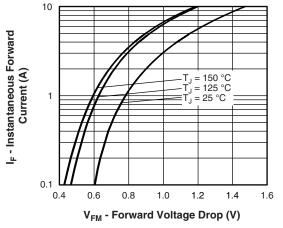


Fig. 1 - Maximum Forward Voltage Drop Characteristics

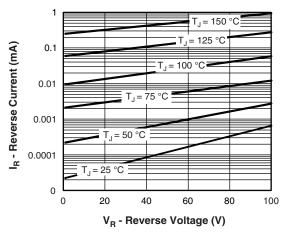


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

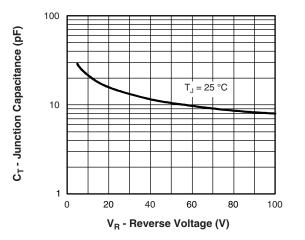
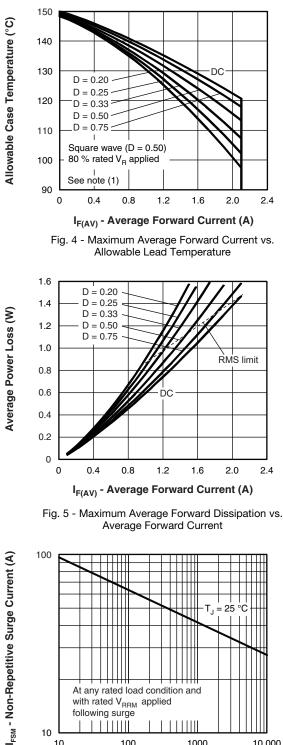


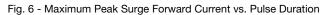
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

VS-10MQ100NTRPbF

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At any rated load condition and with rated V_{RRM} applied following surge 10 10 100 1000 10 000 t_p - Square Wave Pulse Duration (µs)



Note

Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; (1)

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = 80 % rated V_R

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3

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VS-10MQ100NTRPbF





ORDERING INFORMATION TABLE

Device code	VS-	10	м	Q	100	N	TR	PbF
	1	2	3	4	5	6	7	8
	1	- Visl	hay Sen	niconduo	ctors pro	oduct		
	2	- Cur	rent rati	ng (10 =	= 1 A)			
	3	- M =	SMA					
	4	- Q=	Schottk	ky "Q" se	eries			
	5	- Vol	tage rati	ng (100	= 100 \	/)		
	6	- N=	new SN	ΛA				
	7	- TR	= tape a	nd reel				
	8	- PbF	= = lead	(Pb)-fre	е			

ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10MQ100NTRPbF	5AT	7500	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95400			
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			
SPICE model	www.vishay.com/doc?95371			



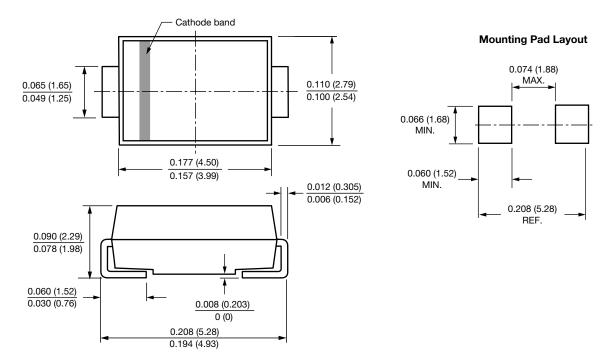
Outline Dimensions

Vishay Semiconductors

SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)





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